



EYP-RWE-0920-04010-1500-SOT02-0000

Revision 1.01

Absolute Maximum Ratings

GAIN CHIPS AR coated Fabry-Perot Laser



General Product Information	
Product	Application
tunable 920 nm Fabry-Perot Laser	Spectroscopy
(



for use in an External Cavity Diode Laser (ECDL) sealed SOT Housing Monitor Diode

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _S	°C	-20		85
Operational Temperature at Case	T _C	°C	-20		50
Forward Current	I _F	mA			190
Reverse Voltage	V_R	V			0
Output Power (extracavity)	P _{opt}	mW			50

Measurement Conditions / Comments	
Stress in excess of the Absolute Maximum Rating	JS
can cause permanent damage to the device.	

Recommended Operational Cor	nditions				
Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		40
Forward Current	I _F	mA			180

Measurement Conditions / Comments

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Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm		905	
Tuning Range	$\Delta \lambda_{\text{tun}}$	nm	894		920
Output Power	P_{opt}	mW		30	
Polarization				TE	
Spatial Mode (transversal)				TEM00	
Monitor Detector Responsivity	I_{mon} / P_{ASE}	μΑ/mW	2		40

Characteristics at 25 °C at BOL, with external cavity

under recommended working condition

are strongly influ	ed wavelength and power enced by the external cavity. rantee on these parameters.	
E field parallel to	o Pin 2 - Pin 3 - plane	
Fundamental M	ode	
$U_{RMD} = 5 \text{ V}$		



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Chip Parameter					
Parameter	Symbol	Unit	min	typ	max
Cavity Length	L	μm		1500	
Reflectivity at Front Facet	R_{ff}		3.10-4	3·10 ⁻⁴	1·10 ⁻³

Measurement Conditions / Comments

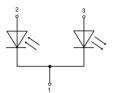
Package Dimensions

Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	h	mm	3.50	3.65	3.70
Excentricity of Emission Center	R	mm			0.12
Pin Length	L _{PIN}	mm		14	

Measurement Conditions / Comments
reference plane: top side of TO header
reference: center of outer diameter of header

Package Pinout

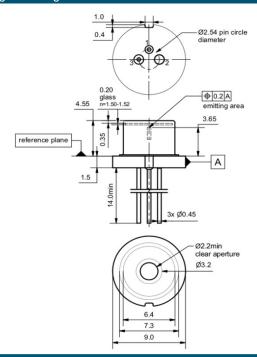
- 1 Laser Diode Cathode, Monitor Diode Cathode, Case
- 2 Photo Diode Anode
- 3 Laser Diode Anode



M-type



Package Drawings





AIZ-16-0421-1517

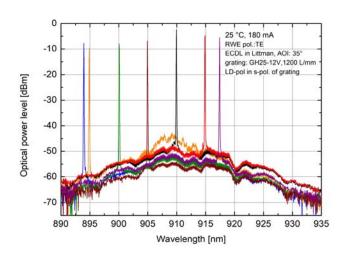
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Typical Measurement Results



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract.

In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPA diode type is known to be sensitive against thermal stress. It should not be operated without appropriate injection from a seed laser. Operating at moderate temperatures on proper heat sinks willI contribute to a long lifetime of the diode. The chip should be protected against moisture. A water vapor content below 5000 ppm is recommended for applications with high reliability requirements.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.













